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Neutron Radiation and Recovery Studies on SiPMs

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SiPM lost its performance characteristics when exposed to high dose of neutrons. However, the distinct hallmark of SiPMs, low dark count and excellent photon-number-resolving capability, can be recovered by thermal annealing. Several Hamamatsu and FBK series SiPMs are characterized before and after exposure of up to 1010 neutron/cm2 dosage using a 14 MeV neutron generation source. Collectively, we established that the typical orders of magnitude increase in dark current upon neutron irradiation can be lowered substantially after processing them with a novel thermal annealing procedure, and single-photon detection are to some extent recovered. Moreover, we found no significant difference on neutron damaged behavior when SiPMs are irradiated at room or liquid nitrogen temperatures.

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